

Red LED



L11767 series

High output power red emitting diode

The L11767 series are high output red LEDs that deliver light output more than twice that of our previous products. Electric power required to provide the same brightness as the previous products is reduced by as much as 70%. The L11767 series also offer high reliability since they are 4-element (AlGaInP) LEDs.

Features

Applications

▶ High radiant output power (more than twice compared to previous products) L11767: 13 mW typ. (IF=20 mA) L11767-0066L: 7.0 mW typ. (IF=20 mA) Optical switches, etc.

High reliability

Structure

Parameter	Symbol	Condition	L11767	L11767-0066L	Unit
Package	-		ТО	-	
Reflector	-		No	Yes	-
Window material	-		Resin	Borosilicate glass	-
AR coating	-		No		
Lens	-		No	Spherical	-

♣ Absolute maximum ratings (Ta=25 °C unless otherwise noted)

Parameter	Symbol	Condition	L11767	L11767-0066L	Unit
Reverse voltage	VR		5		V
Forward current	IF		6	mA	
Derating rate of forward current	-	Ta > 25 °C	0.8		mA/°C
Pulse forward current	IFP	Pulse width=10 µs Duty ratio=1%	0	А	
Derating rate of pulse forward current	-	Ta > 25 °C	6.7		mA/°C
Power dissipation	Р		180		mW
Operating temperature	Topr		-30 to +85		°C
Storage temperature	Tstg	*1	-40 to +100		°C
Soldering condition	-		Less than 260 °C, within 5 seconds *2		

^{*1:} Guaranteed to resist temperature cycle test of up to 5 cycles (L11767 only)

Note: Exceeding the absolute maximum ratings even momentarily may cause a drop in product quality. Always be sure to use the product within the absolute maximum ratings.

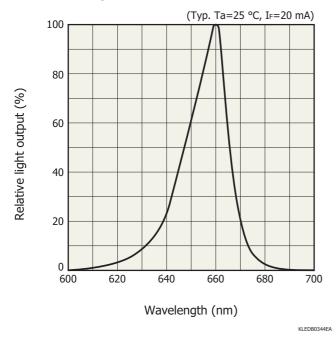
^{*2:} At a position at least 1 mm away from the lead base

Electrical and optical characteristics (Ta=25 °C)

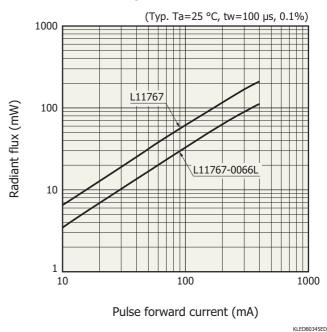
Parameter	Symbol Condition	Condition	L11767			L11767-0066L			Unit
		Condition	Min.	Тур.	Max.	Min.	Тур.	Max.	Offic
Peak emission wavelength	λр	IF=20 mA	650	660	670	650	660	670	nm
Spectral half-width	Δλ	IF=20 mA	-	18	30	-	18	30	nm
Forward voltage	VF	IF=20 mA	-	2.1	2.5	-	2.1	2.5	V
Reverse current	IR	VR=5 V	-	-	20	-	-	20	μA
Radiant flux	φе	IF=20 mA	10	13	-	5	7	-	mW
Cutoff frequency*3	fc	IF=20 mA \pm 1 mAp-p	3	6	-	3	6	-	MHz

^{*3:} Frequency at which the light output drops by 3 dB relative to the output at 100 kHz

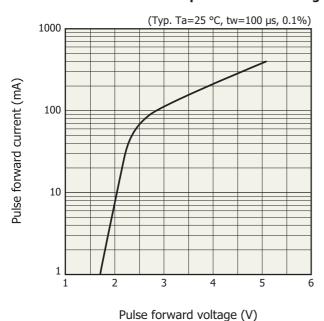
Emission spectrum



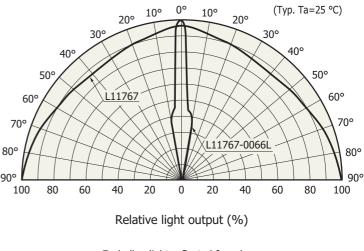
- Radiant flux vs. pulse forward current



Pulse forward current vs. pulse forward voltage



Directivity



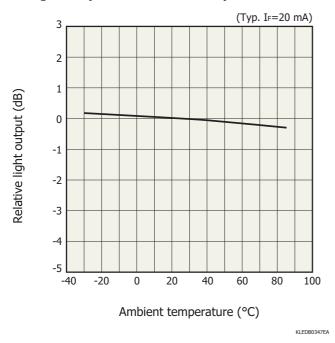
Excluding light reflected from base

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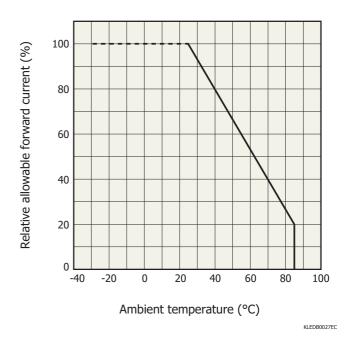


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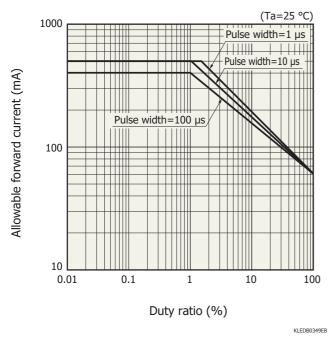
Light output vs. ambient temperature



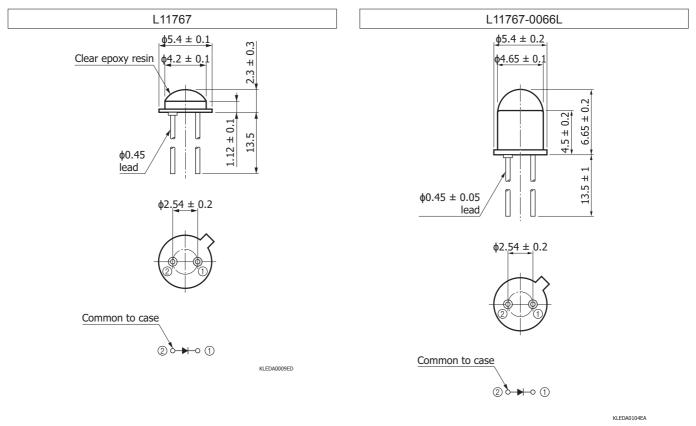
- Allowable forward current vs. ambient temperature



Allowable forward current vs. duty ratio



Dimensional outlines (unit: mm)



Related information

www.hamamatsu.com/sp/ssd/doc_en.html

- Precautions
- · Disclaimer
- · Metal, ceramic, plastic products

Information described in this material is current as of October 2016.

Product specifications are subject to change without prior notice due to improvements or other reasons. This document has been carefully prepared and the information contained is believed to be accurate. In rare cases, however, there may be inaccuracies such as text errors. Before using these products, always contact us for the delivery specification sheet to check the latest specifications.

The product warranty is valid for one year after delivery and is limited to product repair or replacement for defects discovered and reported to us within that one year period. However, even if within the warranty period we accept absolutely no liability for any loss caused by natural disasters or improper product use. Copying or reprinting the contents described in this material in whole or in part is prohibited without our prior permission.

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